MWI 75-06 A7
MWI 75-06 A7 T

## IGBT Modules <br> Sixpack

Short Circuit SOA Capability Square RBSOA

| Type | NTC - Option |
| :--- | :--- |
| MWI 75-06 A7 | without NTC |
| MWI 75-06 A7T | with NTC |


| $\mathrm{I}_{\text {C25 }}$ | $=90 \mathrm{~A}$ |
| :--- | :--- |
| $\mathrm{~V}_{\text {CES }}$ | $=600 \mathrm{~V}$ |
| $\mathrm{~V}_{\text {CE(sat) ty. }}$ | $=\mathbf{2 . 1} \mathrm{V}$ |



See outline drawing for pin arrangement


Symbol Conditions
Characteristic Values ( $T_{\mathrm{Vd}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. max.


Features

- NPT IGBT technology - Iow saturation voltage
- low switching losses
- switching frequency up to 30 kHz
- square RBSOA, no latch up
- high short circuit capability
- positive temperature coefficient for easy parallelling
- MOS input, voltage controlled
- ultra fast free wheeling diodes
- solderable pins for PCB mounting
- package with copper base plate


## Advantages

- space savings
- reduced protection circuits
- package designed for wave soldering


## Typical Applications

- AC motor control
- AC servo and robot drives
- power supplies

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| Diodes |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Conditions | Maximum Ratings |  |  |  |
| $\mathrm{I}_{\text {F25 }}$ <br> $\mathrm{I}_{\text {F80 }}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=80^{\circ} \mathrm{C} \end{aligned}$ | $\begin{array}{r} 140 \\ 85 \end{array}$ |  | A <br> A |  |
|  |  |  |  |  |  |
| Symbol | Conditions | Characteristic Values |  |  |  |
|  |  |  |  |  |  |  |  |
| $V_{F}$ | $\begin{array}{r} \mathrm{I}_{\mathrm{F}}=75 \mathrm{~A} ; \mathrm{V}_{\mathrm{GE}}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{V} J}=25^{\circ} \mathrm{C} \\ \mathrm{~T}_{\mathrm{V} J}=125^{\circ} \mathrm{C} \end{array}$ |  | 1.8 | 2.1 | V |
|  |  |  | 1.3 |  |  |
| $\begin{aligned} & \mathrm{I}_{\mathrm{RM}} \\ & \mathrm{t}_{\mathrm{rr}} \end{aligned}$ |  |  | 28 | Ans |  |
|  |  |  | 100 |  |  |  |
| $\mathrm{R}_{\text {thJc }}$ | (per diode) |  |  | 0.61 K/W |  |


| Symbol | Conditions | Characteristic Values min. typ. ${ }^{\text {max. }}$ |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |
| $\mathrm{R}_{25}$ | $\mathrm{T}=25^{\circ} \mathrm{C}$ | 4.75 | 5.0 | $5.25 \mathrm{k} \Omega$ |
| $\mathrm{B}_{25 / 50}$ |  |  | 3375 |  |


| Module |  |  |  |
| :---: | :---: | :---: | :---: |
| Symbol | Conditions | Maximum |  |
| $\begin{array}{lr} \hline \mathbf{T}_{\text {vJ }} & -40 \ldots+ \\ \mathbf{T}_{\text {stg }} & -40 \ldots+ \\ \hline \end{array}$ |  |  |  |
| $\mathrm{V}_{\text {ISOL }}$ | $\mathrm{I}_{\text {ISoL }} \leq 1 \mathrm{~mA} ; 50 / 60 \mathrm{~Hz}$ | 2500 | $\mathrm{V} \sim$ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting torque (M5) | 2.7-3.3 | Nm |

## Symbol Conditions

|  |  | min. | typ. |
| :--- | :--- | :---: | ---: |
| $\mathbf{R}_{\text {pin-chip }}$ |  | 5 | max. |
| $\mathbf{d}_{\mathbf{s}}$ | Creepage distance on surface | 6 |  |
| $\mathbf{d}_{\mathbf{A}}$ | Strike distance in air | 6 | mm |
| $\mathbf{R}_{\text {thCH }}$ | with heatsink compound |  | mm |
| Weight |  | 0.02 | $\mathrm{~K} / \mathrm{W}$ |

Equivalent Circuits for Simulation

## Conduction



IGBT (typ. at $\mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} ; \mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ )

$$
V_{0}=0.95 \mathrm{~V} ; R_{0}=20 \mathrm{~m} \Omega
$$

Free Wheeling Diode (typ. at $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ )

$$
V_{0}=1.014 \mathrm{~V} ; R_{0}=4 \mathrm{~m} \Omega
$$

## Thermal Response



Dimensions in mm ( $1 \mathrm{~mm}=\mathbf{0 . 0 3 9 4}{ }^{\text {" }) ~}$


Higher magnification on page B3-72

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Fig. 1 Typ. output characteristics


Fig. 3 Typ. transfer characteristics


Fig. 5 Typ. turn on gate charge


Fig. 2 Typ. output characteristics


Fig. 4 Typ. forward characteristics of free wheeling diode


Fig. 6 Typ. turn off characteristics of free wheeling diode


Fig. 7 Typ. turn on energy and switching times versus collector current


Fig. 9 Typ. turn on energy and switching times versus gate resistor


Fig. 11 Reverse biased safe operating area RBSOA


Fig. 8 Typ. turn off energy and switching times versus collector current


Fig. 10 Typ. turn off energy and switching times versus gate resistor


Fig. 12 Typ. transient thermal impedance

## X-ON Electronics

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F3L400R07ME4_B22 F4-50R07W2H3_B51 FB15R06W1E3 FB20R06W1E3_B11 FD1000R33HE3-K FD400R12KE3 FD400R33KF2C-K FD401R17KF6C_B2 FD-DF80R12W1H3_B52 FF200R06YE3 FF300R12KE4_E FF450R12ME4P FF600R12IP4V FP20R06W1E3 FP50R12KT3 FP75R07N2E4_B11 FS10R12YE3 FS150R07PE4 FS150R12PT4 FS200R12KT4R FS50R07N2E4_B11 FZ1000R33HE3 FZ1800R17KF4 DD250S65K3 DF1000R17IE4 DF1000R17IE4D_B2 DF1400R12IP4D DF200R12PT4_B6 DF400R07PE4R_B6 BSM75GB120DN2_E3223c-Se F3L300R12ME4_B22 F3L75R07W2E3_B11 F4-50R12KS4_B11 F475R07W1H3B11ABOMA1 FD1400R12IP4D FD200R12PT4_B6 FD800R33KF2C-K FF1200R17KP4_B2 FF150R12ME3G FF300R17KE3_S4 FF300R17ME4_B11 FF401R17KF6C_B2 FF650R17IE4D_B2 FF900R12IP4D FF900R12IP4DV STGIF7CH60TS-L FP50R07N2E4_B11 FS100R07PE4 FS150R07N3E4_B11 FS150R17N3E4

